Supporting Information for

High entropy effect on thermoelectric properties of nonequilibrium cubic phase of $AgBiSe_{2-2x}S_xTe_x$ with $x = 0–0.6$

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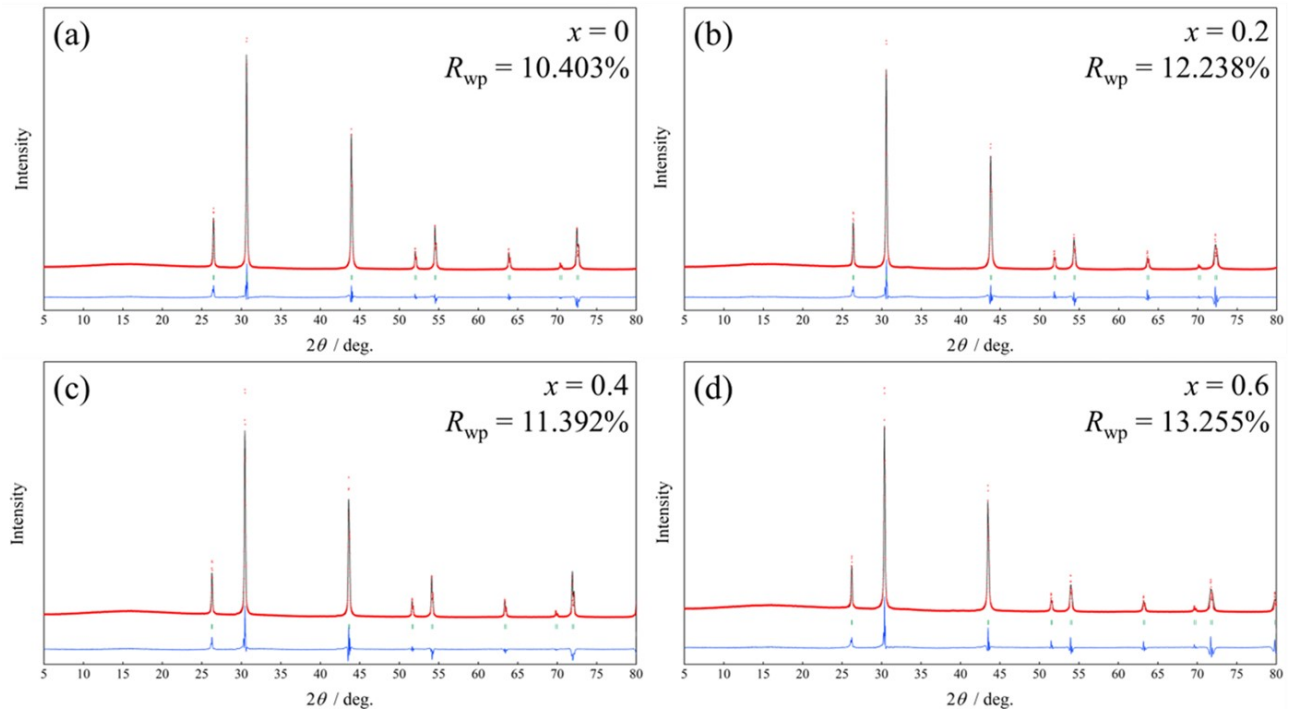

Fig. S1 The result of Rietveld refinement for quenched $AgBiSe_{2-2x}S_xTe_x$ samples.

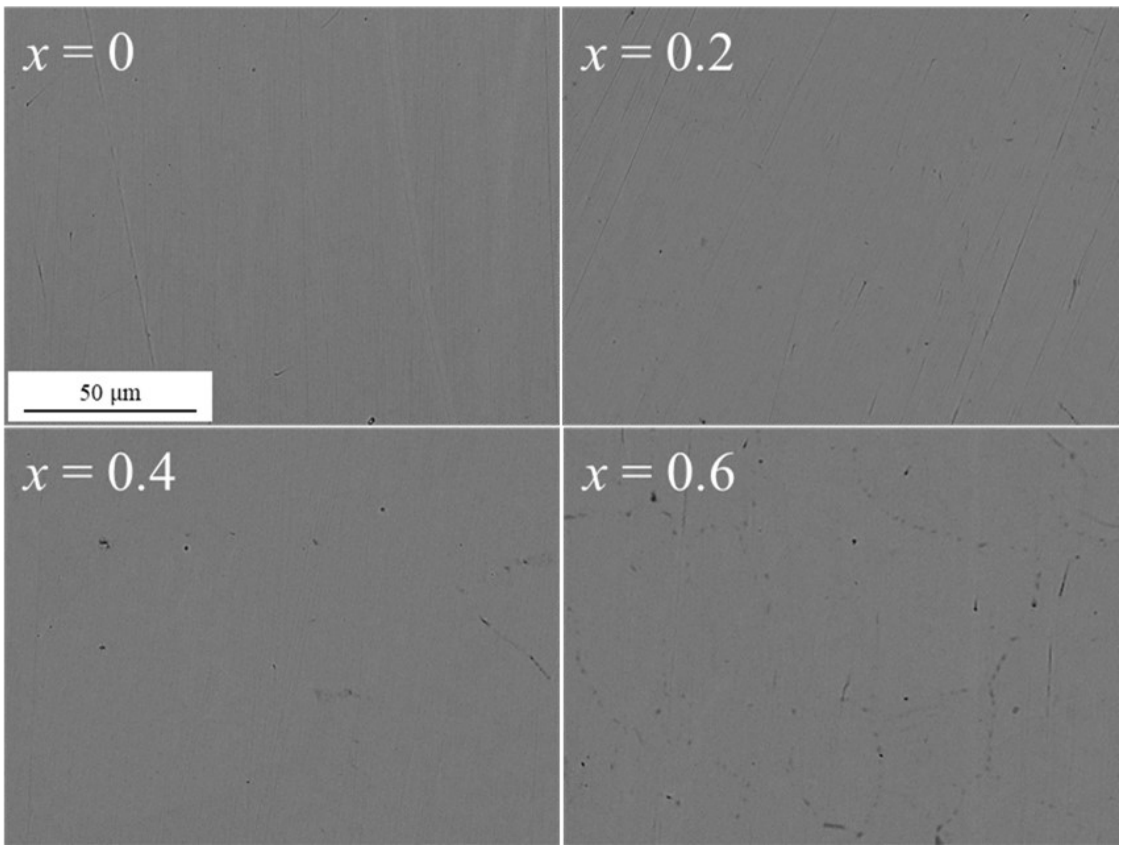

Fig. S2 SEM images for quenched $AgBiSe_{2-2x}S_xTe_x$ samples.

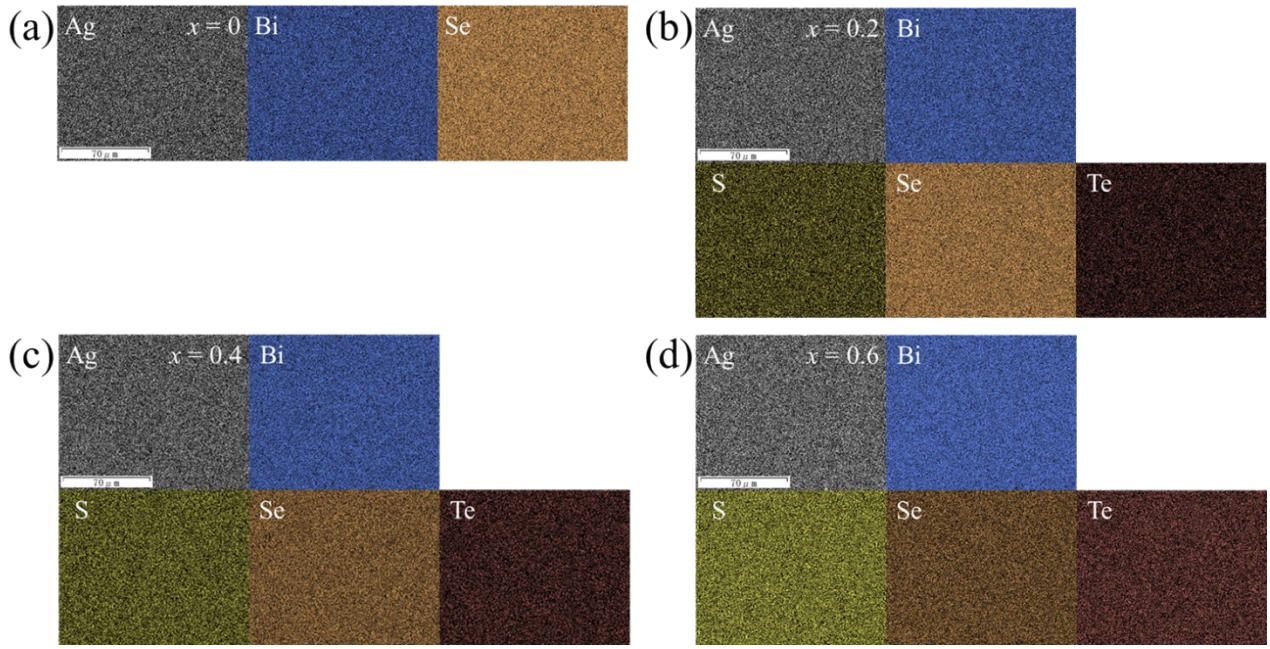

Fig. S3 EDX mapping for quenched $AgBiSe_{2-2x}S_xTe_x$ samples.

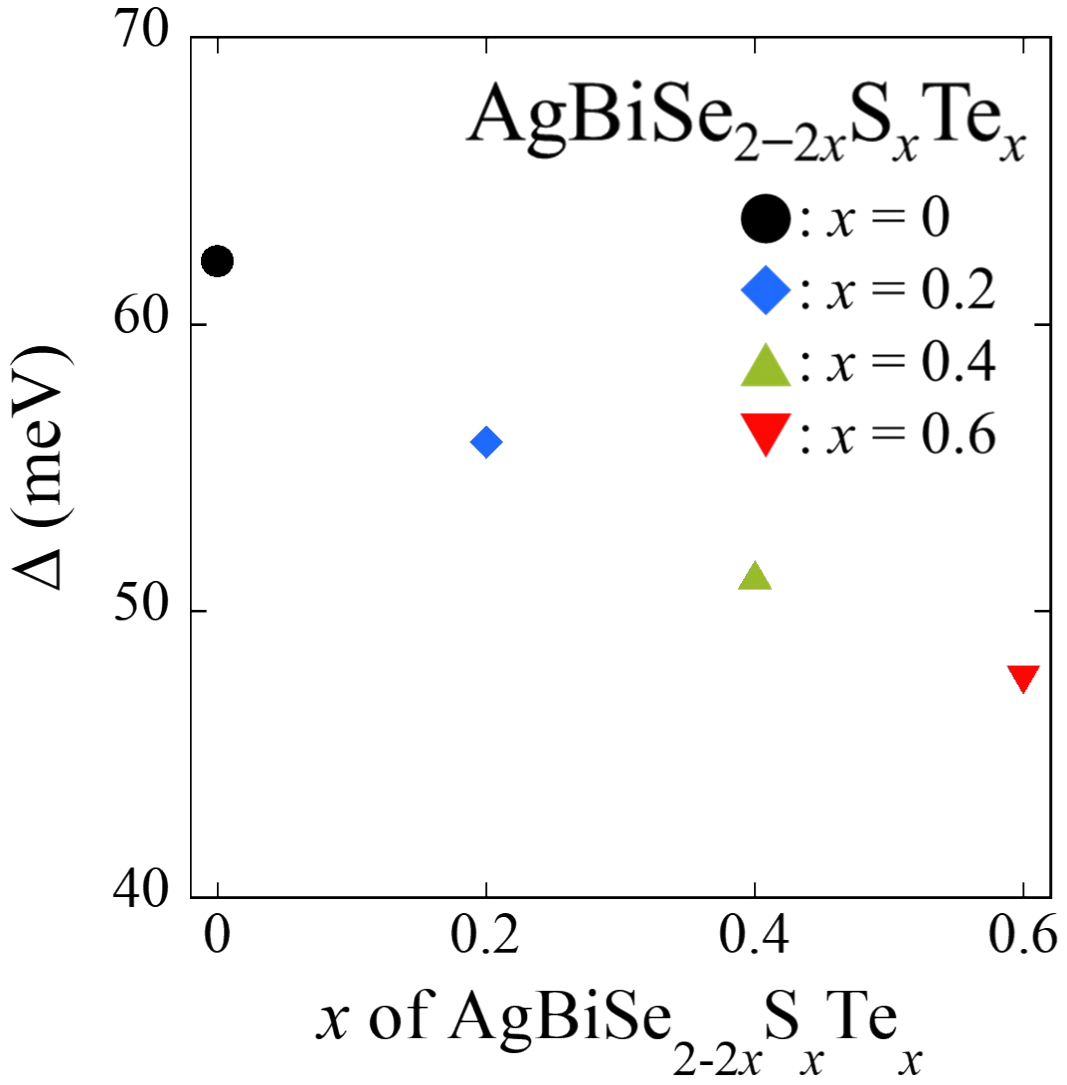

Fig. S4 Activation energy (Δ) of electrical resistivity for quenched $AgBiSe_{2-2x}S_xTe_x$ samples.

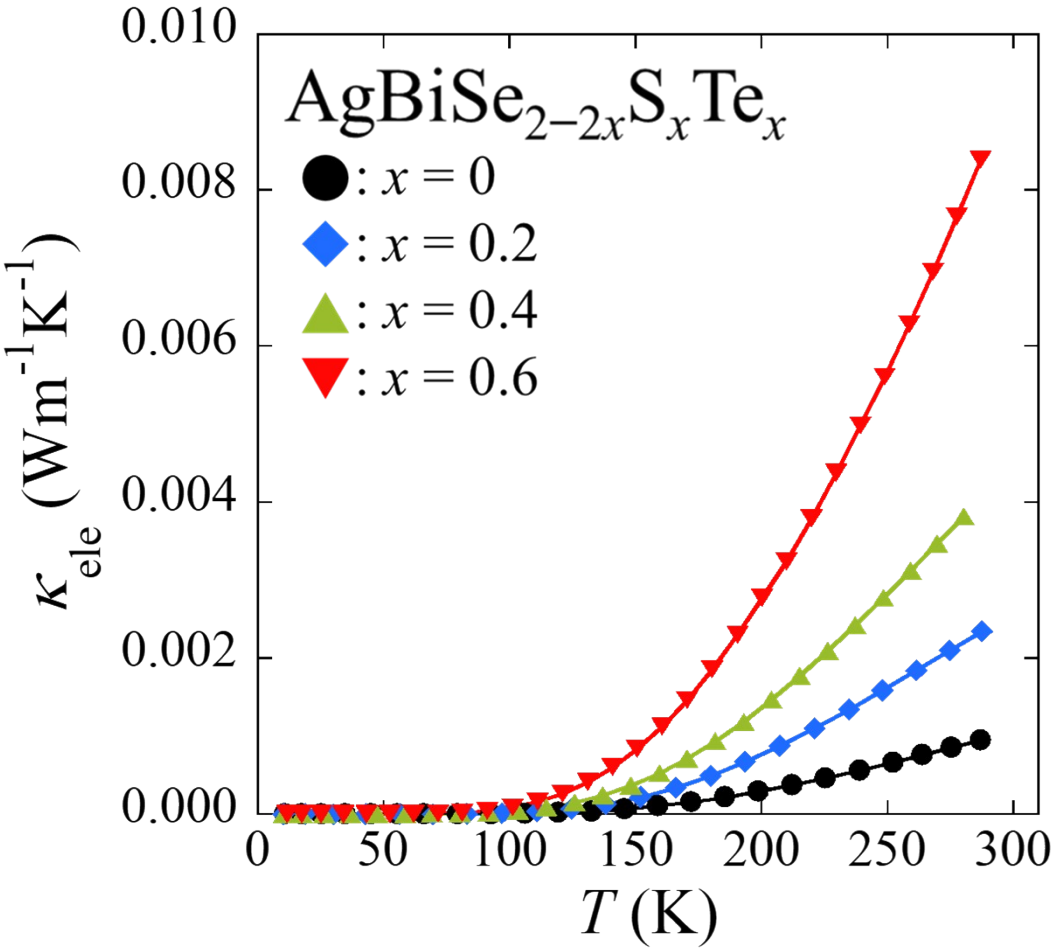

Fig. S5 Temperature (T) dependence of electronic thermal conductivity (κ_{ele}) for quenched $AgBiSe_{2-2x}S_xTe_x$ samples.

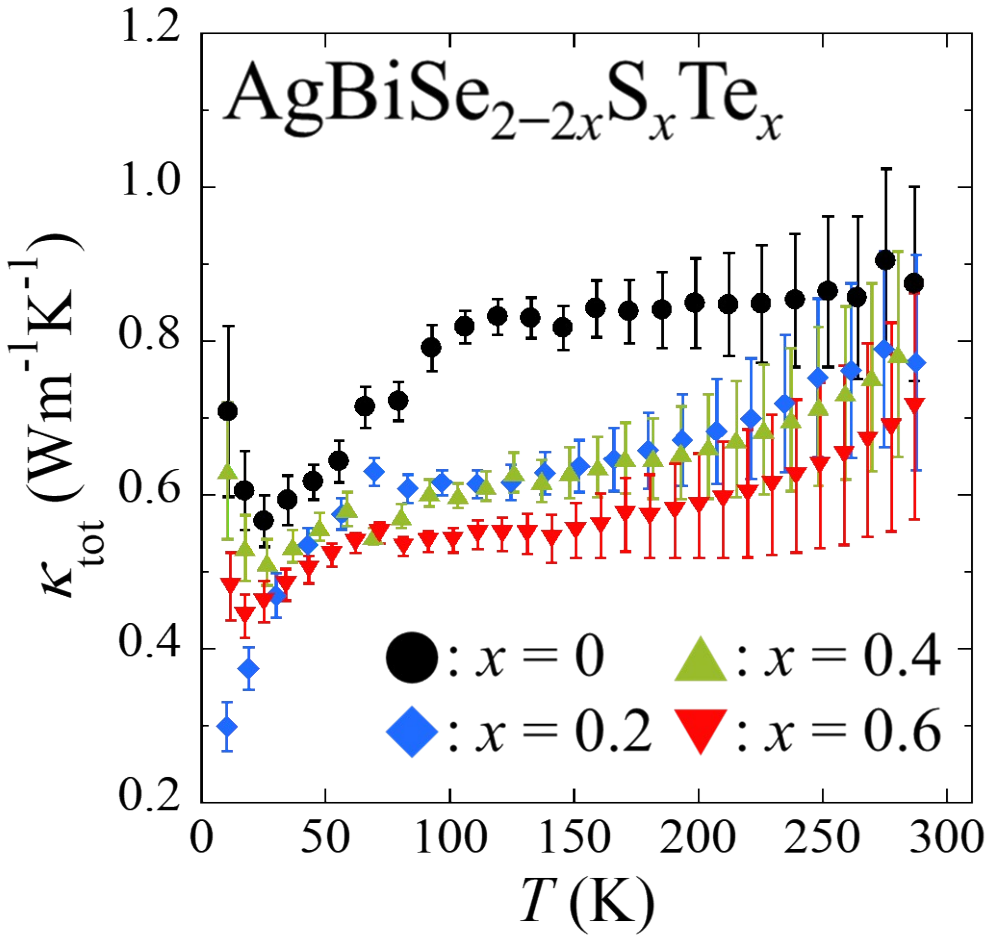

Fig. S6 Temperature dependence (T) of total thermal conductivity (κ_{tot}) with error bar for quenched $AgBiSe_{2-2x}S_xTe_x$ samples.